

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>				Docket Number (Optional) 50478-3700		Application Number 10/591153		30 AUG 2006 Not yet assigned			
				Applicant(s) Hideo Nagai et al.						10/591153	
				Filing Date Herewith				Group Art Unit Not yet assigned			
U. S. PATENT DOCUMENTS											
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE				
		6,222,207	4.24.2001	Carter-Coman et al.							
		6,316,785	11.13.2001	Nunoue et al.							
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EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE				
		2004-0031956	2.19.2004	Saxler							
FOREIGN PATENT DOCUMENTS											
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation YES NO				
		2003-110138	4.11.2003	Japan w/English Abstract			X				
		11-330552	11.30.1999	Japan w/English Abstract			X				
OTHER DOCUMENTS <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>											
		Yamada, Motokazu et al; InGaN-Based Near-Ultraviolet and Blue-Light-Emitting Diodes with High External Quantum Efficiency Using a Patterned Sapphire Substrate and a Mesh Electrode; Jpn. J. Appl. Phys Vol. 41 (2002) pp. L1431-L1433, Part 2, No. 12B, December 15, 2002, The Japan Society of Applied Physics.									
EXAMINER				DATE CONSIDERED							
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